

**PATENT APPLICATION**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Docket No: Q80822

Masatomo SHIBATA

Allowed: June 21, 2007

Appln. No.: 10/813,176

Group Art Unit: 2813

Confirmation No.: 4446

Examiner: Jennifer M. Dolan

Filed: March 31, 2004

For: III-V NITRIDE SEMICONDUCTOR SUBSTRATE AND ITS PRODUCTION METHOD

**AMENDMENT UNDER 37 C.F.R. §1.312**

**MAIL STOP ISSUE FEE**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

*Amend - OK - to enter*

*Jmb 8/30/07*

Sir:

Pursuant to the provisions of 37 C.F.R. §1.312, please amend the above-identified application as follows on the accompanying pages.

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